NSN 5962-01-016-7275

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-016-7275
Body Length:
Between 0.365 inches and 0.385 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.035 inches and 0.070 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
Features Provided:
Hermetically sealed and high speed and programmable and programmed and w/buffered output and w/decoded output and w/enable and
3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
94117-310403 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 flat leads
Shelf Life:
N/a
Unit Of Measure:

Fiig: A458a0

Demilitarization: Yes - demil/mli